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## Visualizing strongly-correlated electrons with a novel scanning tunneling microscope

Battisti, I.

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# VISUALIZING STRONGLY-CORRELATED ELECTRONS WITH A NOVEL SCANNING TUNNELING MICROSCOPE

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IRENE BATTISTI

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in 1990

Promotor:	Prof. dr. J. Aarts	Universiteit Leiden
Co-promotor:	Dr. M.P. Allan	Universiteit Leiden
Promotiecommissie:	Prof. dr. P. Wahl	University of St. Andrews
	Prof. dr. C. Morais-Smith	Universiteit Utrecht
	Prof. dr. K. Schalm	Universiteit Leiden
	Prof. dr. E.R. Eiel	Universiteit Leiden

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The cover shows a (Fourier-filtered) atomically-resolved STM topographic image measured by the author on  $\text{Sr}_2\text{RhO}_4$ . Few atomic defects act as scatterers for quasiparticles, resulting in the formation of standing waves that interfere with each other. The width of the author name corresponds to a scalebar of 2 nm.

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